

NCE15TD120BD

1200V, 15A, Trench FS II Fast IGBT

General Description

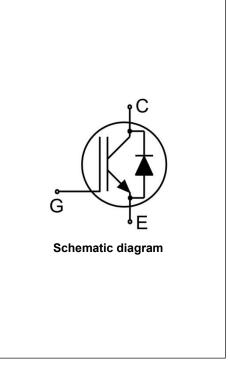
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 1200V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology offering
- Very low V_{CE(sat)}
- High speed switching
- Positive temperature coefficient in V_{CE(sat)}
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Air Condition
- Inverters
- Motor drives



Package Marking and Ordering Information

<u> </u>		
Device	Device Package	Device Marking
NCE15TD120BD	TO-263	NCE15TD120BD



TO-263

Absolute Maximum Ratings (T_c=25°C unless otherwise noted)

Symbol	Parameter	Value	Units V	
V _{CES}	Collector-Emitter Voltage	1200		
V _{GES}	Gate- Emitter Voltage	±30	V	
	Collector Current	30	A	
lc	Collector Current @Tc = 100 °C	15	A	
I _{Cpuls}	Pulsed Collector Current, t _p limited by T _{jmax}	45	A	
- turn off safe operating area, V_{CE} =1200V, T_j =175°C I _F Diode Continuous Forward Current @T _C = 100 °C		45	A	
		15	A	
I _{FM}	Diode Maximum Forward Current	45	A	
Po	Power Dissipation @ T _c = 25°C	300	W	
	Power Dissipation @T _c = 100 °C	150	W	
T_{J},T_{stg}	Operating Junction and Storage Temperature Range	-55 to +175	°C	
$\begin{tabular}{ c c c c }\hline T_L & Maximum Temperature for Soldering & \\ \hline $Short circuit withstand time V_{GE}=15.0V, V_{CC} \leq 600V, $Allowed number of short circuits$<1000Time between $short circuits$:\geq1.0s,T_j \leq 150°C $ \end{tabular}$		260	°C	
		10	us	



NCE15TD120BD

Thermal Characteristic

Symbol	Parameter	Value	Units
Reuc Thermal Resistance, Junction to case for IGBT		0.50	°C/W
Rejc	Thermal Resistance, Junction to case for Diode	0.94	°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	40	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)

Ourse had	Deveneration	Conditions		Value			
Symbol	Parameter			Min.	Тур.	Max.	Units
Static Chara	cteristics					1 1	
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V	I _{CE} =1mA	1200			V
ICES	Collector-Emitter Leakage Current	V _{GE} =0V,\	/ _{CE} =1200V			100	uA
I _{GES(F)}	Gate to Emitter Forward Leakage	V _{GE} =+30	V,V _{CE} =0V			200	nA
I _{GES(R)}	Gate to Emitter Reverse Leakage	V _{GE} =-30\	/,V _{CE} =0V			200	nA
M	Collector-Emitter Saturation Voltage	V_{GE} =15V,	T _j =25°C		1.55	1.80	V
V _{CE(sat)}	Collector-Emitter Saturation voltage	Ic=15A	T _j =175°C		1.80		V
$V_{\text{GE(th)}}$	Gate Threshold Voltage	I _C =1mA,	V _{CE} =V _{GE}	5.0		6.5	V
Dynamic Cha	aracteristics						
Cies	Input Capacitance	V -20V			1430		
Coes	Output Capacitance	V _{CE} =30V,V _{GE} =0V, f=1MHz			35		pF
Cres	Reverse Transfer Capacitance				25		
Qg	Total Gate Charge	Vcc=600V, Ic=15A V _{GE} =15V			90		nC
Q _{ge}	Gate to Emitter Charge				11		nC
Q _{gc}	Gate to Collector Charge	V GE	100		58		nC
I _{C(SC)}	Short circuit collector current Max.1000 short circuits Time between short circuits: ≥1.0s	V _{GE} =15V,V _{CC} ≪600V, t _{SC} ≪10us,Tj≪150°C			80		А
Switching Cl	haracteristics						
$t_{d(ON)}$	Turn-on Delay Time				19		
tr	Rise Time	V _{CE} =600V,I _C =15A V _{GE} =0/15V, R _g =8Ω Inductive Load			17		n 0
$t_{\text{d}(\text{OFF})}$	Turn-Off Delay Time				170		ns
t _f	Fall Time				18		
Eon	Turn-On Switching Loss				0.9		
E _{off}	Turn-Off Switching Loss				0.6		mJ
E _{ts}	Total Switching Loss				1.5		

Electrical Characteristics of the Diode (Tc= 25°C unless otherwise specified)

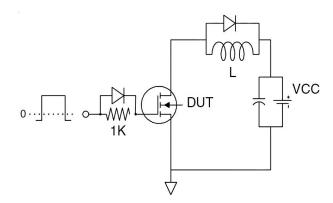
Symbol	Parameter	Conditions	Rating			Unite
		Conditions	Min.	Тур.	Max.	Units
V_{FM}	Diode Forward Voltage	I _F =15A		2.2	2.8	V
Trr	Reverse Recovery Time	ent I⊧=15A, di/dt=200A/us		120		ns
I _{RRM}	Diode Peak Reverse Recovery Current			12		А
Q _{rr}	Reverse Recovery Charge			0.72		uC
Pulse width t _{tp} ≤380μs,δ≤2%						





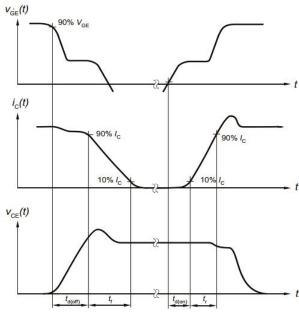
Test Circuit

1) Gate Charge Test Circuit

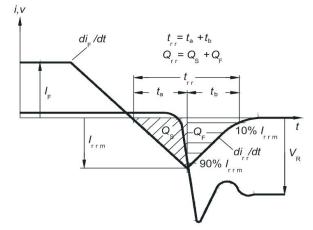


Switching characteristics

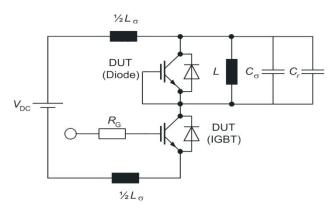
1) Definition of switching times



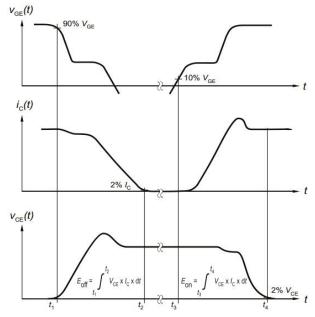
3) Definition of diode switching characteristics



2) Switch Time Test Circuit

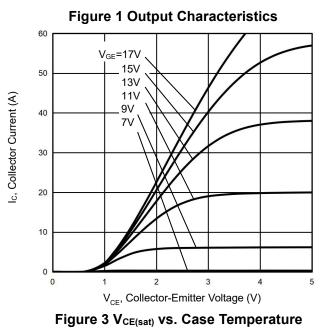


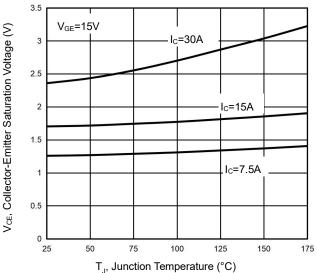
2) Definition of switching losses



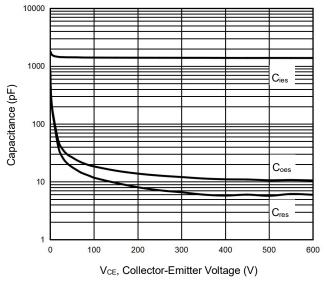


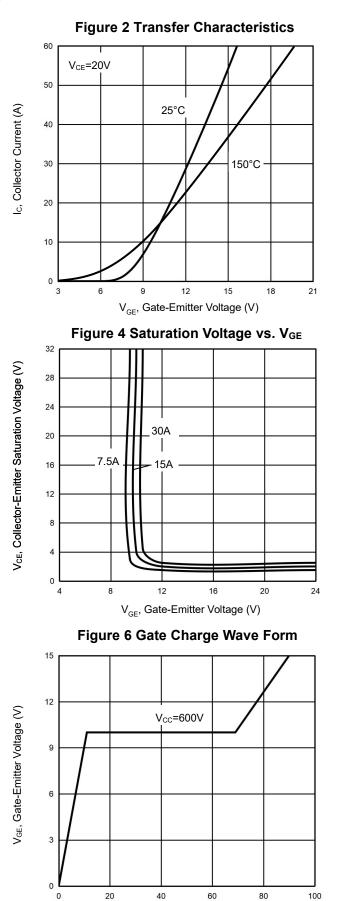
Typical Electrical and Thermal Characteristics







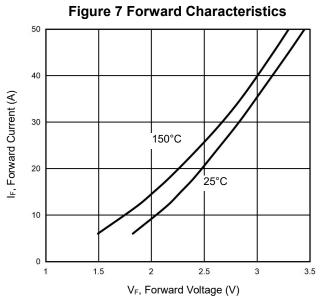




Q_G, Total Gate Charge (nC)



Typical Electrical and Thermal Characteristics





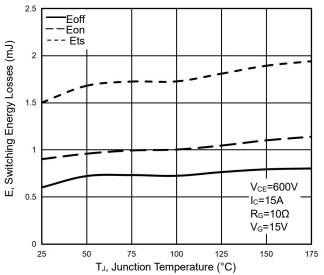
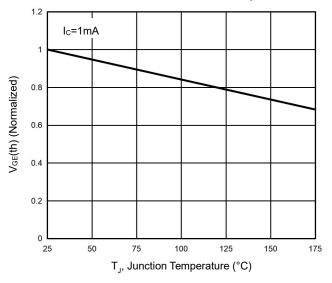


Figure 11 Gate-Emitter Threshold Voltage as a Function of Junction Temperature



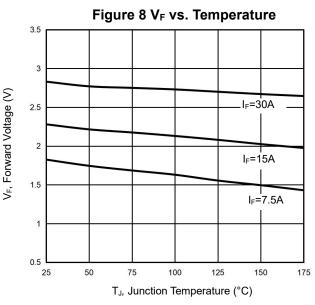


Figure 10 Forward Bias Safe Operating Area

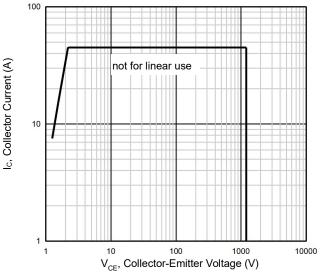
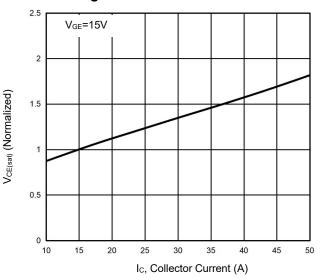
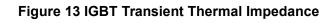


Figure 12 Typical Collector-Emitter Saturation Voltage as a function of Collector Current





Typical Electrical and Thermal Characteristics



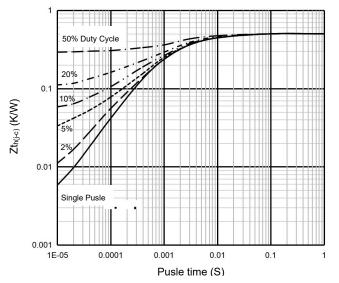
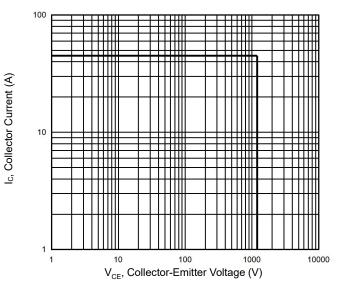
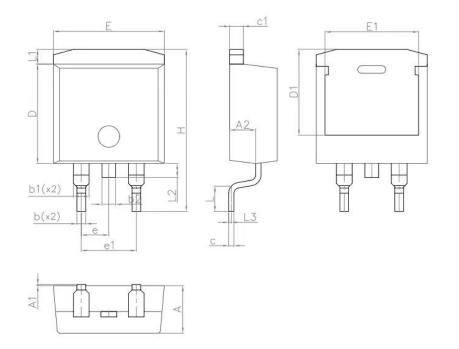


Figure 14 Reverse Bias SOA





TO-263-E Package Information



Symphol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.20	4.60	0.17	0.18	
A1	0.00	0.25	0.00	0.01	
A2	2.20	2.60	0.09	0.10	
b	0.70	0.90	0.03	0.04	
b1	1.20	1.75	0.05	0.07	
b2	1.17	1.37	0.05	0.06	
С	0.40	0.60	0.02	0.03	
c1	1.15	1.40	0.05	0.06	
D	9.10	9.30	0.36	0.37	
D1	7.63	8.23	0.30	0.32	
E	10.05	10.45	0.40	0.41	
E1	8.35	8.95	0.33	0.35	
е	2.54	BSC	0.10	BSC	
e1	5.08	5.08 BSC 0.20 BSC			
н	14.61	15.88	0.58	0.63	
L	1.78	2.79	0.07	0.11	
L1	1.36 REF				
L2	1.30 REF				
L3		0.:	25 REF		





Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.